Thyristor Semiconductor Device - Page 1 of 1



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Inclosure Material:
Metal
Overall Length:
0.340 inches
Overall Diameter:
0.620 inches
Mounting Facility Quantity:
2
Internal Configuration:
Junction contact
Electrode Internally-electrically Connected To Case:
Anode
Mounting Method:
Unthreaded hole
Features Provided:
Hermetically sealed case
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
200.0 breakover voltage, dc
Current Rating Per Characteristic:
60.00 amperes forward current, average absolute
Power Rating Per Characteristic:
5.0 watts small-signal input power, common-collector blank
Maximum Operating Tempurature Per Measurement Point:
100.0 degrees celsius junction
Special Features:
Junction pattern arrangement: pnpn
Terminal Type And Quantity:
2 pin and 1 case
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
Fiig. A110a0
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